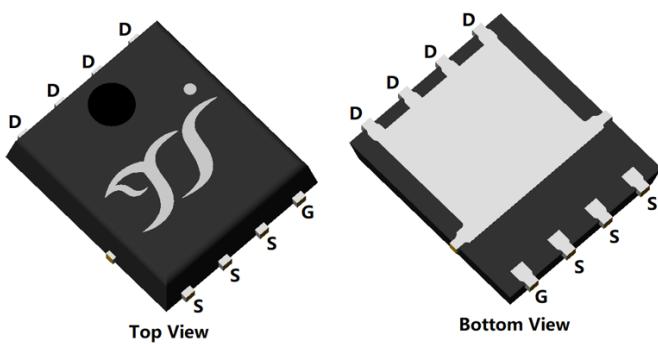
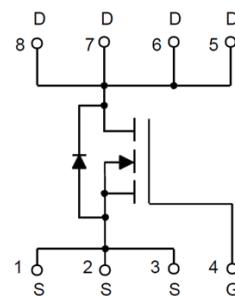


N-Channel Enhancement Mode Field Effect Transistor



PDFN5060-8L



Product Summary

- V_{DS} 40 V
- I_D 18 A
- $R_{DS(ON)}$ (at $V_{GS} = 10V$) $< 14 \text{ mohm}$
- $R_{DS(ON)}$ (at $V_{GS} = 4.5V$) $< 19 \text{ mohm}$
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 3
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- High current load applications
- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	40	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current $T_c=25^\circ\text{C}$	I_D	18	A
$T_c=100^\circ\text{C}$		11	
Pulsed Drain Current ^A	I_{DM}	75	A
Total Power Dissipation $T_c=25^\circ\text{C}$	P_D	17	W
$T_c=100^\circ\text{C}$		7	W
Single Pulse Avalanche Energy ^B	E_{AS}	49	mJ
Thermal Resistance Junction-to-Case ^C	$R_{\theta JC}$	7.1	$^\circ\text{C} / \text{W}$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^\circ\text{C}$

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJG18N04A	F1	YJG18N04A	5000	10000	100000	13" reel

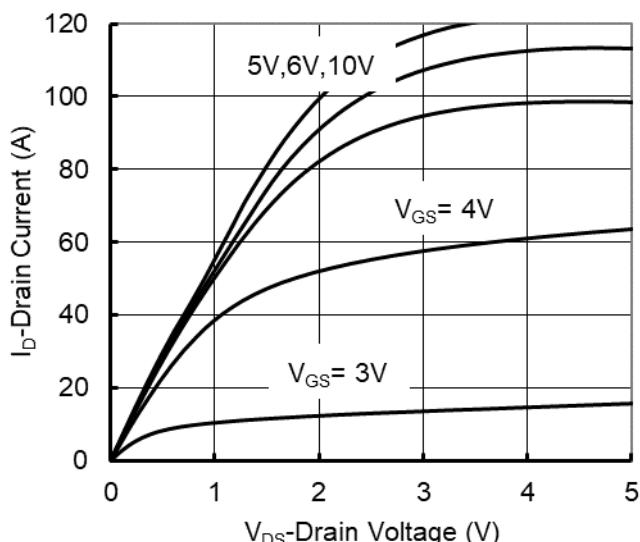
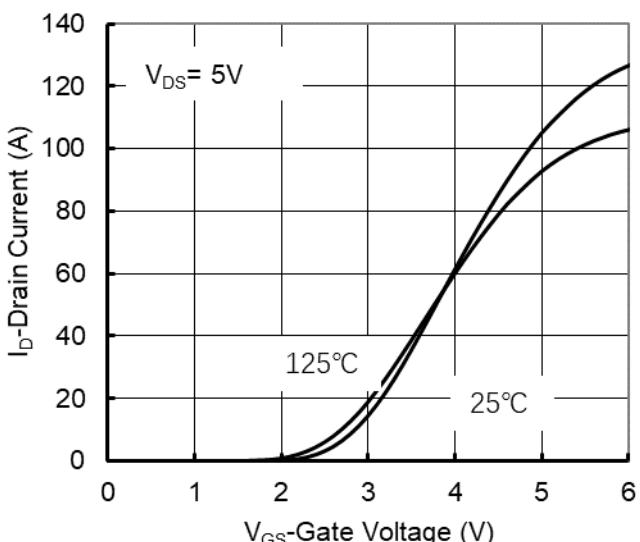
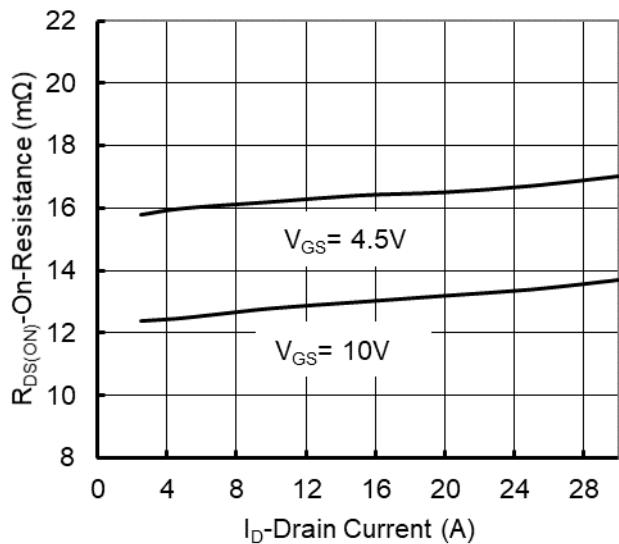
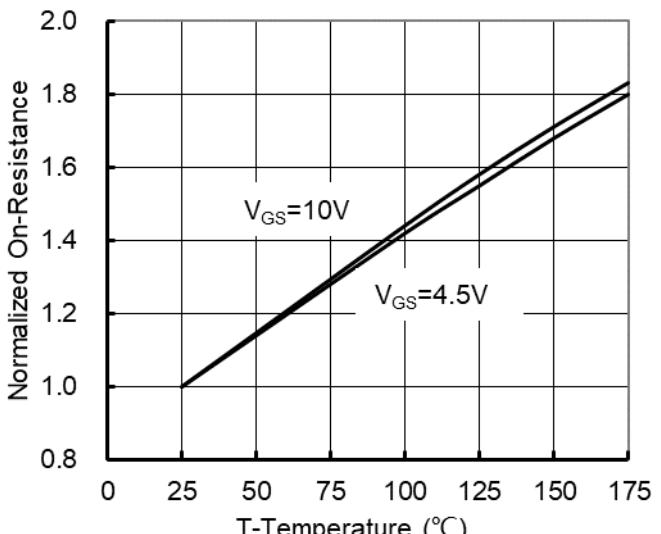
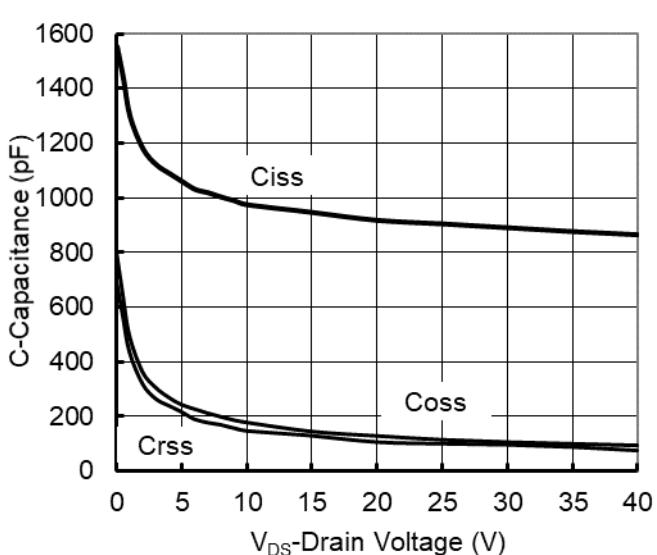
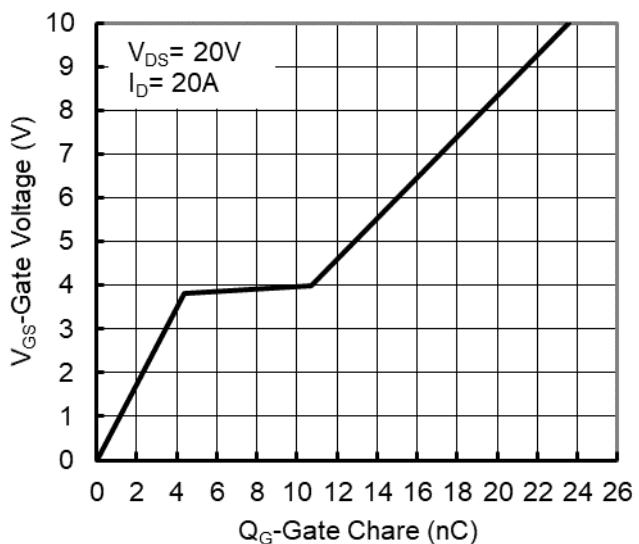


YJG18N04A

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Units
Static Parameter							
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$		40			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=40\text{V}, V_{\text{GS}}=0\text{V}$	$T_J=25^\circ\text{C}$			1	μA
			$T_J=150^\circ\text{C}$			100	
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$				± 100	nA
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$		1.0	1.5	2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=15\text{A}$			11	14	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=10\text{A}$			14	19	
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=15\text{A}, V_{\text{GS}}=0\text{V}$			0.85	1.2	V
Maximum Body-Diode Continuous Current	I_{S}					18	A
Dynamic Parameters							
Input Capacitance	C_{iss}	$V_{\text{DS}}=20\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$			917		pF
Output Capacitance	C_{oss}				128		
Reverse Transfer Capacitance	C_{rss}				108		
Switching Parameters							
Total Gate Charge	Q_{g}	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=20\text{V}, I_{\text{D}}=20\text{A}$			23.6		nC
Gate-Source Charge	Q_{gs}				4.4		
Gate-Drain Charge	Q_{gd}				6.3		
Reverse Recovery Charge	Q_{rr}	$I_{\text{F}}=20\text{A}, \frac{dI}{dt}=100\text{A/us}$			0.4		ns
Reverse Recovery Time	t_{rr}				7		
Turn-on Delay Time	$t_{\text{D(on)}}$				10		
Turn-on Rise Time	t_{r}	$V_{\text{GS}}=10\text{V}, V_{\text{DD}}=20\text{V}, I_{\text{D}}=2\text{A}$ $R_{\text{GEN}}=3\Omega$			56		ns
Turn-off Delay Time	$t_{\text{D(off)}}$				27		
Turn-off fall Time	t_{f}				72		

- A. Pulse Test: Pulse Width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.
- B. $T_J=25^\circ\text{C}$, $V_{\text{DD}}=40\text{V}$, $V_{\text{G}}=10\text{V}$, $L=0.5\text{mH}$, $I_{\text{AS}}=14\text{A}$
- C. R_{\thetaJA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{\thetaJC} is guaranteed by design, while R_{\thetaJA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

Figure 1. Output Characteristics

Figure 2. Transfer Characteristics

Figure 3. On-Resistance vs. Drain Current and Gate Voltage

Figure 4. On-Resistance vs. Junction Temperature

Figure 5. Capacitance Characteristics

Figure 6. Gate Charge

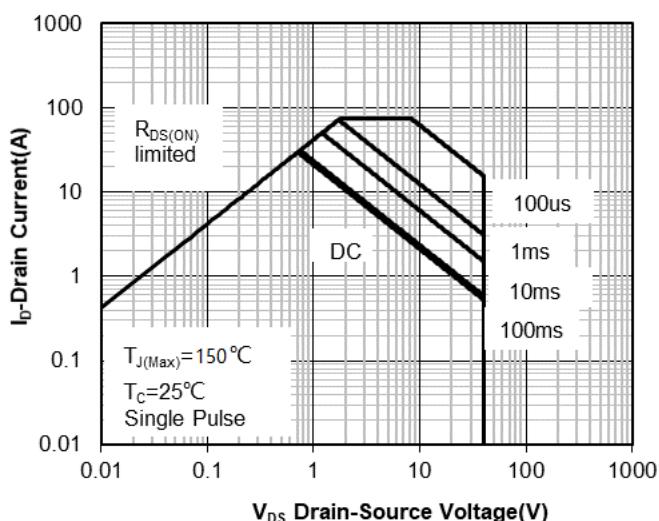


Figure 7. Safe Operation Area

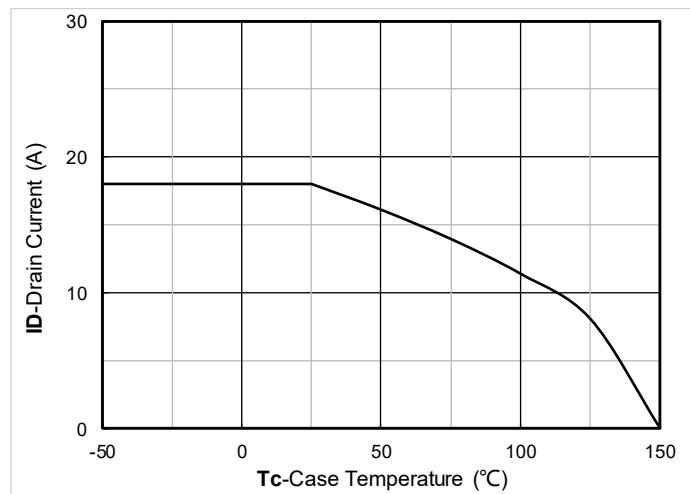


Figure 8. Maximum Continuous Drain Current vs Case Temperature

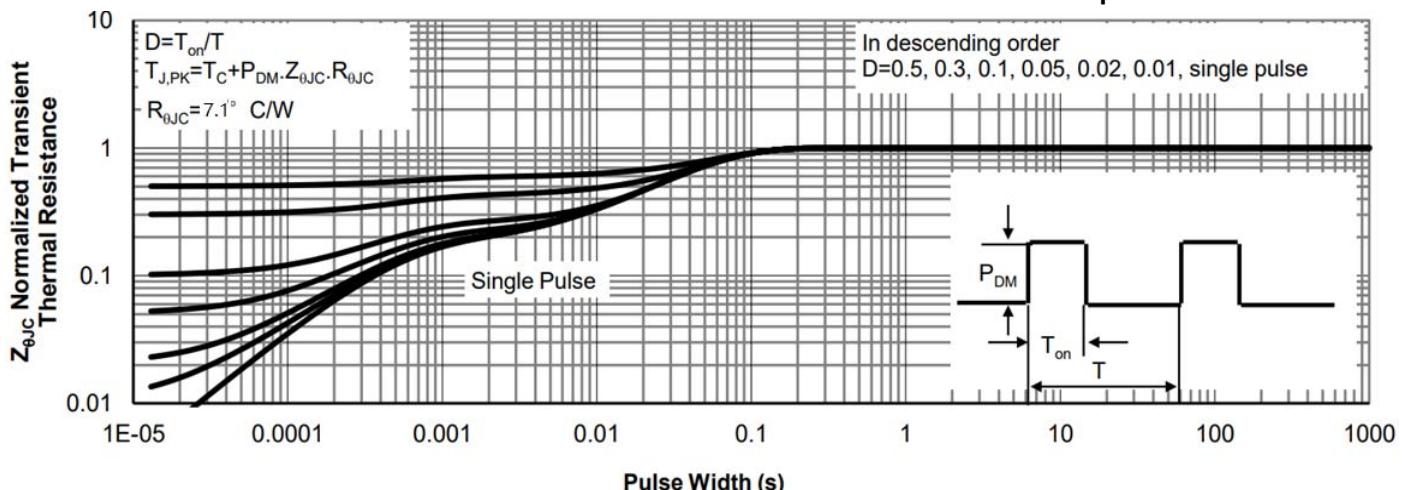
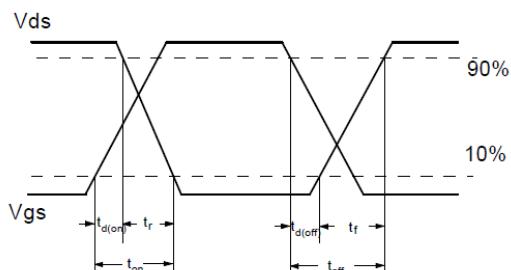
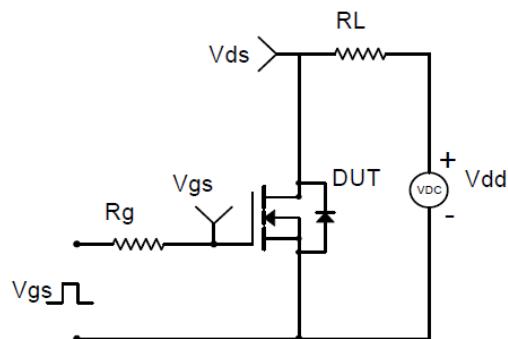
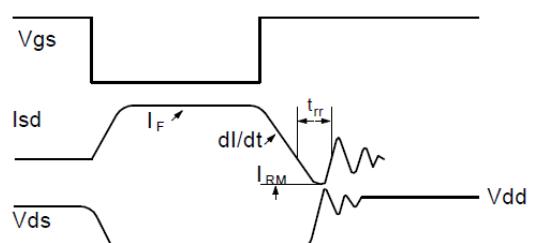
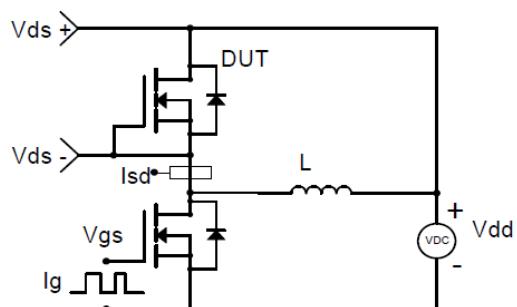
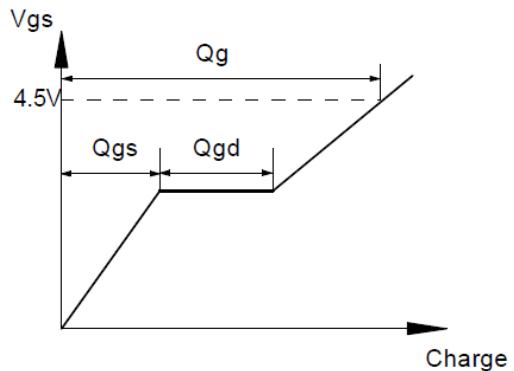
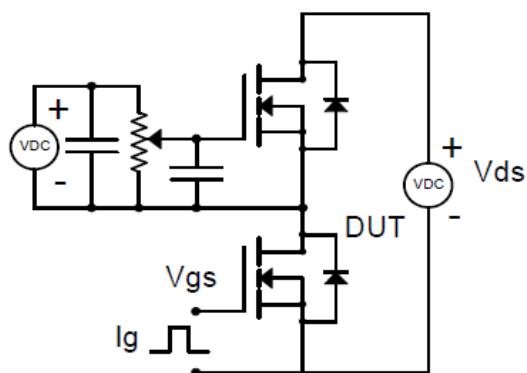
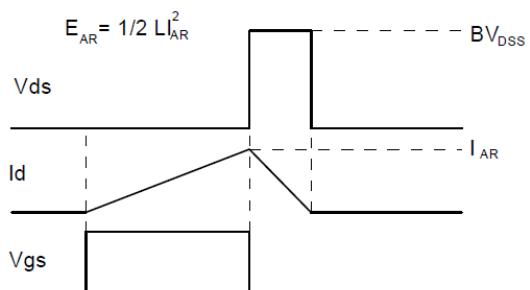
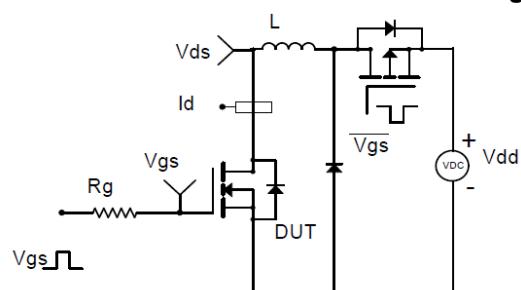
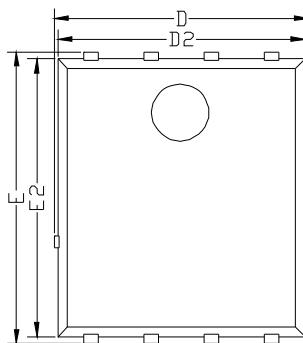
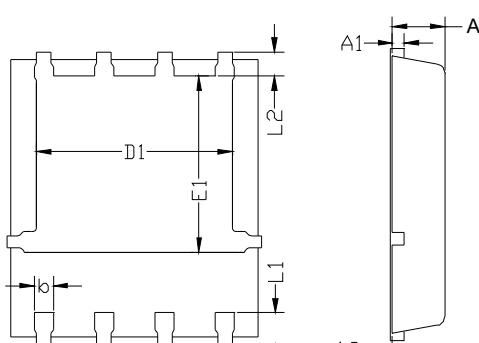
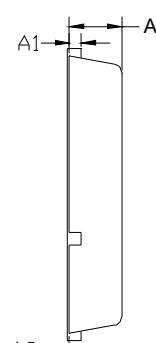
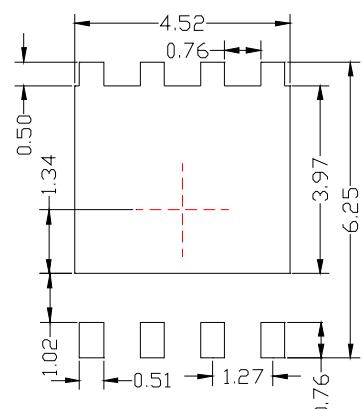


Figure 9. Normalized Maximum Transient Thermal Impedance


Resistive Switching Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms

Gate Charge Test Circuit & Waveform

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



■ PDFN5060-8L Package Information

Top View
正面视图Bottom View
背面视图Side View
侧面视图Suggested Solder Pad Layout
Top View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.15	6.35
A	1.00	1.10	1.20
A1	0.254	BSC	
A2			0.10
D1	3.92	4.12	4.32
E1	3.52	3.72	3.92
D2	5.00	5.20	5.40
E2	5.66	5.86	6.06
L1	0.56	0.66	0.76
L2	0.50	BSC	
b	0.31	0.41	0.51
e	1.27	BSC	

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: +/-0.10mm.
3. The pad layout is for reference purposes only.



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